

USB Drive

3ME Series

Customer:

Customer

Part Number:

Innodisk

Part Number:

Innodisk

Model Name:

Date:

Innodisk Approver	Customer Approver

**The Total Solution For
Industrial Flash Storage**

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REVISION HISTORY

Revision	Description	Date
Pre.	First Release	Apr., 2014
1.0	Modify ECC description	May., 2014
1.1	Add A19 part number	Aug., 2014
1.2	Renew the ROHS Declaration	Oct., 2014
1.3	Remove the Flash endurance SPEC	Jan., 2015
1.4	Add compatibility info. Modify PN rule Remove 4GB, add 64GB	Feb., 2016
1.5	Modify PN rule for 15nm	Mar., 2016
1.6	Modify 16GB performance	May., 2016
1.7	Modify LBA	Aug., 2016
1.8	Update RoHS/REACH/CE/FCC	Apr., 2017
1.9	Update RoHS/REACH certificate Modify golden finger	Nov., 2017
2.0	Update RoHS/REACH certificate	Aug. 2019
2.1	Update Product Photo	Nov. 2019
2.2	Update 128GB product	Mar. 2020
2.3	Update mechanical dimensions drawing Revise storage temperature Remove appendix	Oct., 2021
2.4	Remove 128GB Revise PN rule	Nov., 2022

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1. Product Overview

1.1 Introduction of USB Drive

The Innodisk USB Drive products provide high capacity USB flash memory storage that electrically complies with High-speed USB 3.0 interface & backward compatible with USB 2.0 and 1.1. The device features attractive small form factor and the connectivity over USB3.0 and the NAND flash architecture provide a faster data transmission. In our default setting, the USB Drive will be set up as "Removable mode".

1.2 Product View



Figure 1: USB Drive 3ME

1.3 Product Models

USB Drive 3ME is available in follow capacities.

- USB Drive 3ME 8GB
- USB Drive 3ME 16GB
- USB Drive 3ME 32GB
- USB Drive 3ME 64GB

1.4 Capacity

USB Drive 3ME provides unformatted from 8GB up to 64GB capacities within MLC Flash IC.

2. Theory of operation

2.1 Overview

Figure 2 shows the operation of USB Drive 3ME from the system level, including the major hardware blocks.

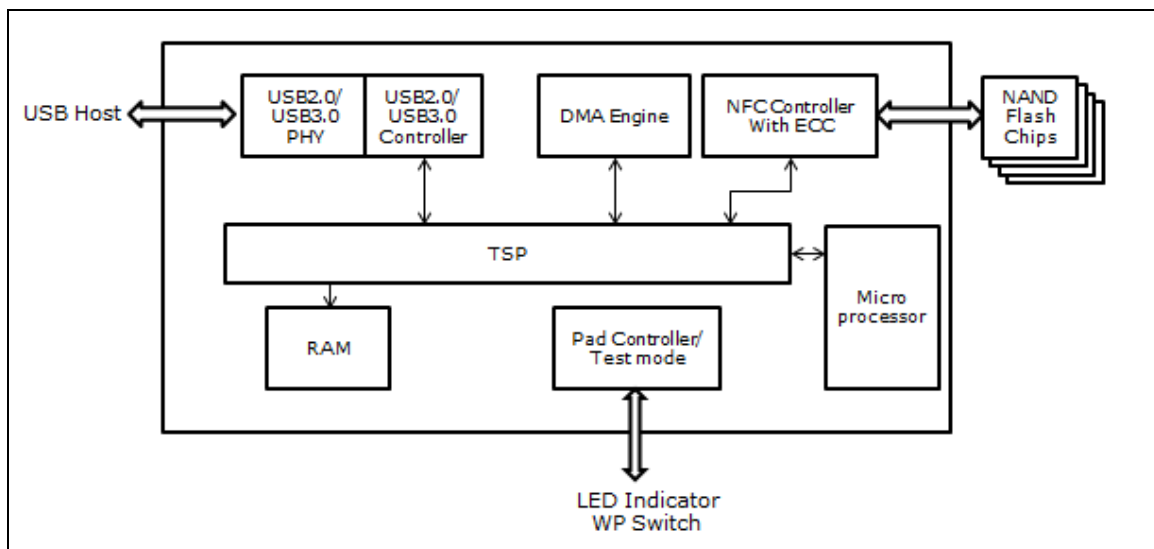


Figure 2: USB Drive 3ME Block Diagram

USB Drive 3ME integrates a USB3.0 controller and NAND flash memories. Communication with the host occurs through the host interface. Communication with the flash device(s) occurs through the flash interface.

2.2 Error Detection and Correction

Highly sophisticated Error Correction Code algorithms are implemented. The ECC unit consists of the Parity Unit (parity-byte generation) and the Syndrome Unit (syndrome-byte computation). This unit implements an algorithm that can correct 60 bits per 1024 bytes in an ECC block. Code-byte generation during write operations, as well as error detection during read operation, is implemented on the fly without any speed penalties.

2.3 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the *erase cycle limit* or *write endurance limit* and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

USB Drive 3ME uses a static wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

2.4 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may generate during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management and replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit. After the reserved block less than 40, the SSD will be locked, and cannot be written anymore.

3. Specifications

3.1 CE and FCC Compatibility

USB Drive 3ME conforms to CE and FCC requirements.

3.2 RoHS Compliance

USB Drive 3ME is fully compliant with RoHS directive.

3.3 Environmental Specifications

3.3.1 Temperature Ranges

Operating Temperature Range:

- Standard Grade: 0°C ~ +70°C
- Industrial Grade: -40°C ~ +85°C

Storage Temperature Range:

- Standard Grade: -40°C to +85°C

3.3.2 Humidity

Relative Humidity: 10-95%, non-condensing

3.3.3 Shock and Vibration

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 68-2-6
Mechanical Shock	Duration: 0.5ms, 1500G, 3 axes	IEC 68-2-27

Table 1: Shock/Vibration Testing for USB Drive 3ME

3.3.4 Mean Time between Failures (MTBF)

Table 2 summarizes the MTBF prediction results for various USB Drive 3ME configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- Failure Rate: The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- Mean Time between Failures (MTBF): A basic measure of reliability for repairable items:

The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Product	Condition	MTBF (Hours)
USB Drive 3ME	Telcordia SR-332 GB, 25°C	>3,000,000

Table 2: USB Drive 3ME MTBF

3.3.5 Terabyte Written (TBW)

Parameter	Value
TBW(Sequential Write)	Unit:TB
8GB	21.6
16GB	43.2
32GB	86.4
64GB	172.8

Table 3: USB Drive 3ME TBW

3.4 Golden finger

Au=3 μ”

3.5 Pin Assignment

USB Drive 3ME is designed within USB3.0 Interface. Particularly, its built-in power pin enables the device more compactable. Table 4 demonstrates USB Drive 3ME pin assignments.

Pin Number	Signal Name	Description
1	VBUS	Power
2	D-	USB 2.0 differential pair
3	D+	
4	GND	Ground for power return
5	StdA_SSRX-	SuperSpeed receiver differential pair
6	StdA_SSRX+	
7	GND_DRAIN	Ground for signal return
8	StdA_SSTX-	SuperSpeed transmitter differential pair
9	StdA_SSTX+	
Shell	Shield	Connector metal shell

Note: Tx and Rx are defined from the host perspective

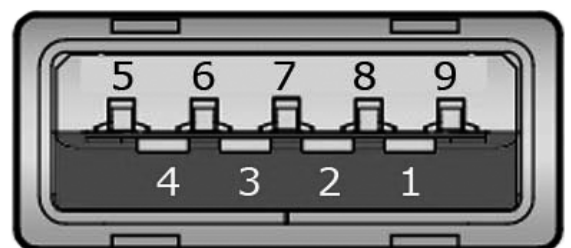


Table 4: USB Drive 3ME Pin Assignment

3.6 Mechanical Dimensions

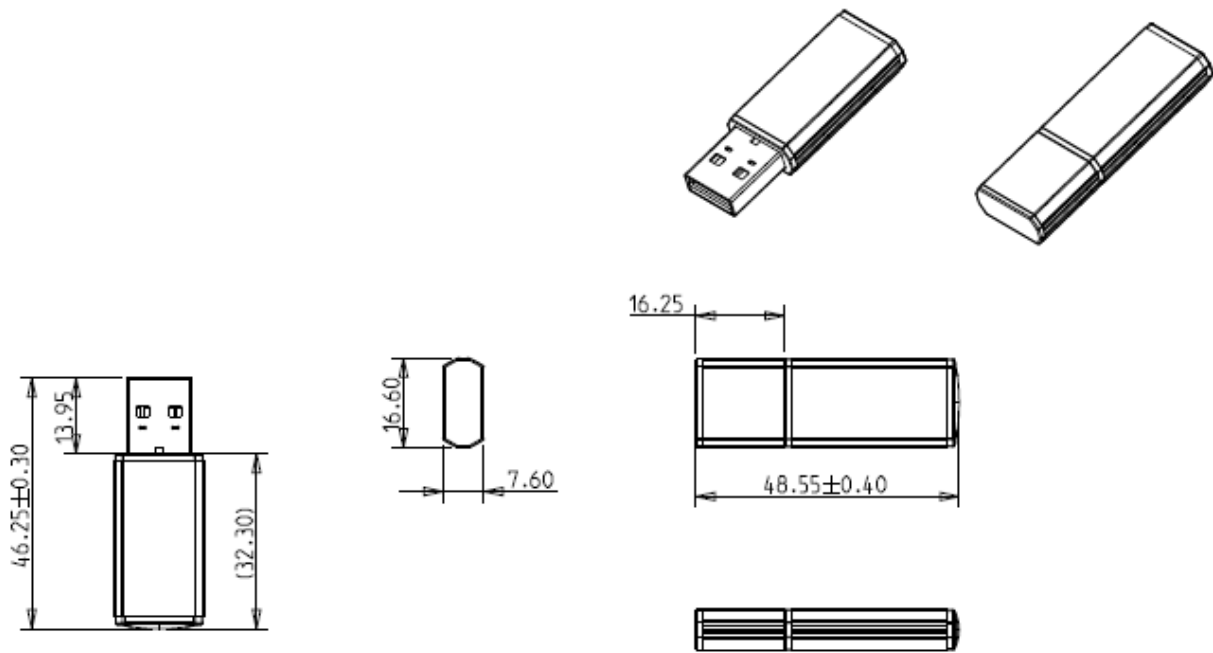


Figure 3: USB Drive 3ME mechanical dimensions

3.7 Weight

10g±2

3.8 Performance

Product name		8GB	16GB	32GB	64GB
USB Drive 3ME	Sequential Read (Max.)	100 MB/S	100 MB/S	100 MB/S	100 MB/S
	Sequential Write (Max.)	25 MB/S	25 MB/S	50 MB/S	50 MB/S

Table 5: USB Drive 3ME performance

3.9 NAND Flash Memory

USB Drive 3ME uses Multi Level Cell (MLC) NAND flash memory, which is non-volatility and high reliability.

4. Electrical Specifications

4.1 Power Requirement

Item	Symbol	Rating	Unit
Input voltage	V_{IN}	+5 DC +- 5%	V

Table 6: USB Drive 3ME Power Requirement

4.2 Power Consumption

Mode	Power Consumption (mA)
Read	122 (max.)
Write	141 (max.)
Idle	67 (max.)

Table 7: Power Consumption

4.3 Device Parameters

Capacity	LBA	User capacity
8GB	15810560	7720MB
16GB	31686656	15472MB
32GB	63373312	30944MB
64GB	126812160	61920MB

Table 8: Device parameters

5. Part Number Rule

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20
	D	E	U	A	1	-	0	8	G	I	6	1	B	C	1	S	C	-	X	X
Description	Disk	Form Factor				-	Capacity			Category			Flash mode	Operation Temp.	PCB Ver.	Channel	Flash Vender	Customized Code		
Definition																				
Code 1st (Disk)						Code 14th (Operation Temperature)														
D: Disk						C: Standard Grade (0°C ~ +70°C)														
Code 2nd ~ 5th (Form Factor)						Code 15th (Internal control)														
EUA1: USB Drive						W: Industrial Grade (-40°C ~ +85°C)														
Code 7th ~9th (Capacity)						1: TSOP PCB version														
08G: 8GB																				
16G: 16GB						Code 16th (Channel)														
32G: 32GB						S: Single														
64G: 64GB																				
Code 10th ~12th (Category)						Code 17th (Flash)														
I61: USB 3ME series						C: Kioxia MLC														
Code 13th (Flash mode)						Code 19~20th (Customized Code)														
B: Sync. Flash (15nm)																				